

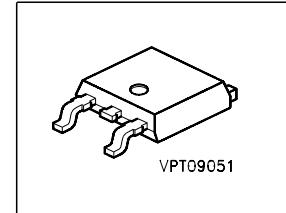
Fast Switching EmCon Diode

Product Summary

V_{RRM}	600	V
I_F	6	A
V_F	1.5	V
T_{jmax}	175	°C

Feature

- 600 V EmCon technology
- Fast recovery
- Soft switching
- Low reverse recovery charge
- Low forward voltage
- 175°C operating temperature
- Easy paralleling
- Pb-free lead plating; RoHS compliant
- Qualified according to JEDEC⁰⁾ for target applications



Type	Package	Ordering Code	Marking	Pin 1	PIN 2,4	PIN 3
IDD06E60		-	D06E60	NC	C	A

Maximum Ratings, at $T_j = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Repetitive peak reverse voltage	V_{RRM}	600	V
Continuous forward current $T_C = 25$ °C	I_F	14.7	A
$T_C = 90$ °C		10	
Surge non repetitive forward current $T_C = 25$ °C, $t_p = 10$ ms, sine halfwave	I_{FSM}	29	A
Maximum repetitive forward current $T_C = 25$ °C, t_p limited by $t_{j,max}$, $D = 0.5$	I_{FRM}	22	A
Power dissipation $T_C = 25$ °C	P_{tot}	46.8	W
$T_C = 90$ °C		26.6	
Operating junction temperature	T_j	-40...+175	
Storage temperature	T_{stg}	-55...+150	°C
Soldering temperature 1.6mm (0.063 in.) from case for 10 s	T_s	260	

Thermal Characteristics

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
Characteristics					
Thermal resistance, junction - case	R_{thJC}	-	-	3.2	K/W
SMD version, device on PCB: @ min. footprint @ 6 cm ² cooling area ¹⁾	R_{thJA}	-	-	75	
		-	-	50	

Electrical Characteristics, at $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
Static Characteristics					
Reverse leakage current $V_R=600\text{V}, T_j=25^\circ\text{C}$ $V_R=600\text{V}, T_j=150^\circ\text{C}$	I_R	-	-	50 500	μA
Forward voltage drop $I_F=6\text{A}, T_j=25^\circ\text{C}$ $I_F=6\text{A}, T_j=150^\circ\text{C}$	V_F	-	1.5 1.5	2 -	V

¹⁾J-STD20 and JESD22

¹⁾Device on 40mm*40mm*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70 μm thick) copper area for drain connection. PCB is vertical without blown air.

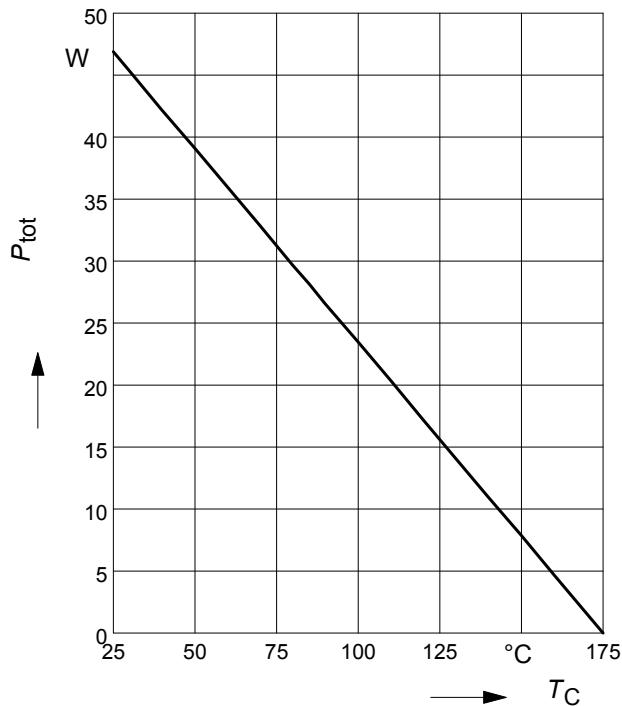
Electrical Characteristics, at $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
Dynamic Characteristics					
Reverse recovery time $V_R=400\text{V}, I_F=6\text{A}, di/dt=550\text{A}/\mu\text{s}, T_j=25^\circ\text{C}$	t_{rr}	-	70	-	ns
$V_R=400\text{V}, I_F=6\text{A}, di/dt=550\text{A}/\mu\text{s}, T_j=125^\circ\text{C}$		-	100	-	
$V_R=400\text{V}, I_F=6\text{A}, di/dt=550\text{A}/\mu\text{s}, T_j=150^\circ\text{C}$		-	105	-	
Peak reverse current $V_R=400\text{V}, I_F=6\text{A}, di/dt=550\text{A}/\mu\text{s}, T_j=25^\circ\text{C}$	I_{rrm}	-	6.5	-	A
$V_R=400\text{V}, I_F=6\text{A}, di/dt=550\text{A}/\mu\text{s}, T_j=125^\circ\text{C}$		-	7.4	-	
$V_R=400\text{V}, I_F=6\text{A}, di/dt=550\text{A}/\mu\text{s}, T_j=150^\circ\text{C}$		-	7.9	-	
Reverse recovery charge $V_R=400\text{V}, I_F=6\text{A}, di/dt=550\text{A}/\mu\text{s}, T_j=25^\circ\text{C}$	Q_{rr}	-	240	-	nC
$V_R=400\text{V}, I_F=6\text{A}, di/dt=550\text{A}/\mu\text{s}, T_j=125^\circ\text{C}$		-	360	-	
$V_R=400\text{V}, I_F=6\text{A}, di/dt=550\text{A}/\mu\text{s}, T_j=150^\circ\text{C}$		-	400	-	
Reverse recovery softness factor $V_R=400\text{V}, I_F=6\text{A}, di_F/dt=550\text{A}/\mu\text{s}, T_j=25^\circ\text{C}$	S	-	4	-	
$V_R=400\text{V}, I_F=6\text{A}, di_F/dt=550\text{A}/\mu\text{s}, T_j=125^\circ\text{C}$		-	4.8	-	
$V_R=400\text{V}, I_F=6\text{A}, di_F/dt=550\text{A}/\mu\text{s}, T_j=150^\circ\text{C}$		-	4.9	-	

1 Power dissipation

$$P_{\text{tot}} = f(T_C)$$

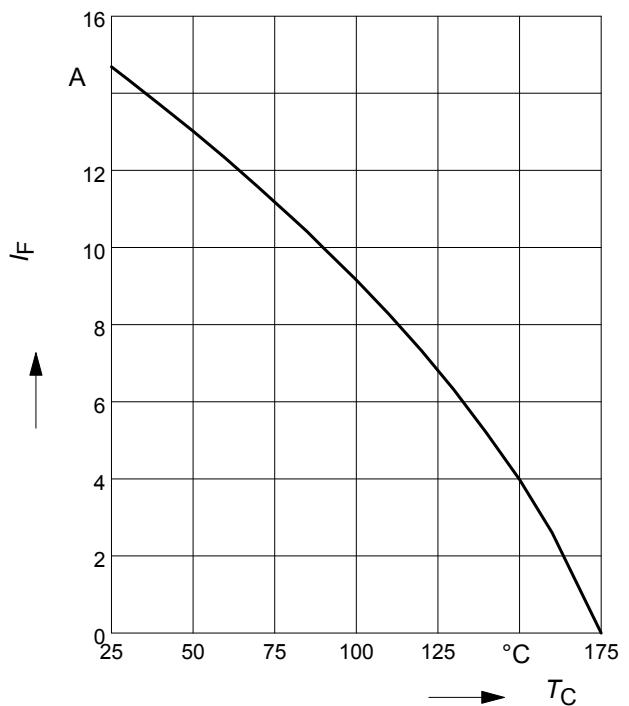
parameter: $T_j \leq 175^\circ\text{C}$



2 Diode forward current

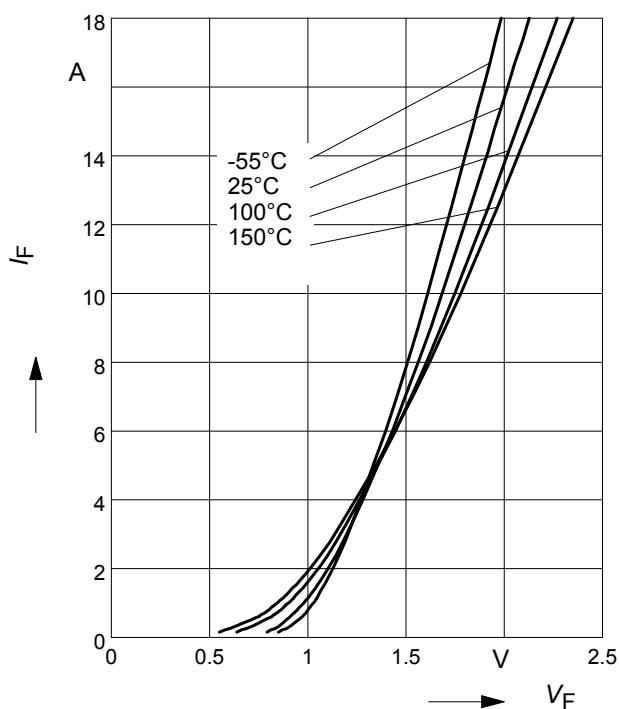
$$I_F = f(T_C)$$

parameter: $T_j \leq 175^\circ\text{C}$



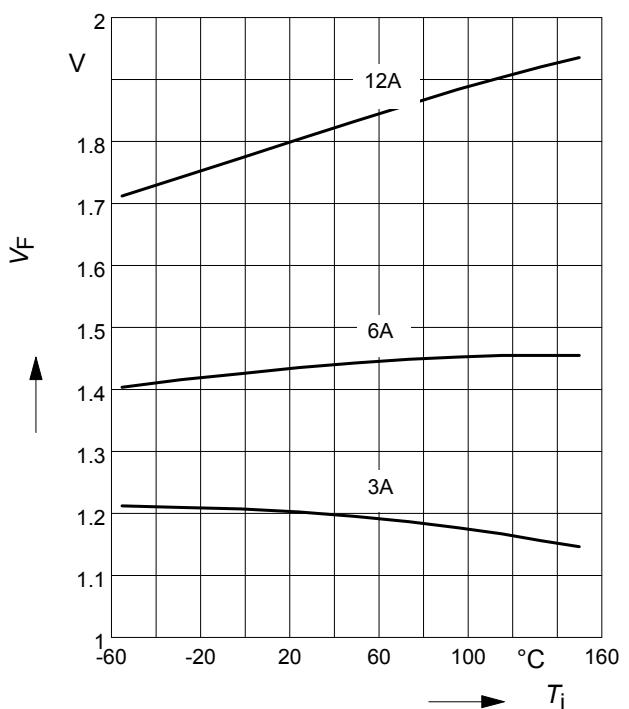
3 Typ. diode forward current

$$I_F = f(V_F)$$



4 Typ. diode forward voltage

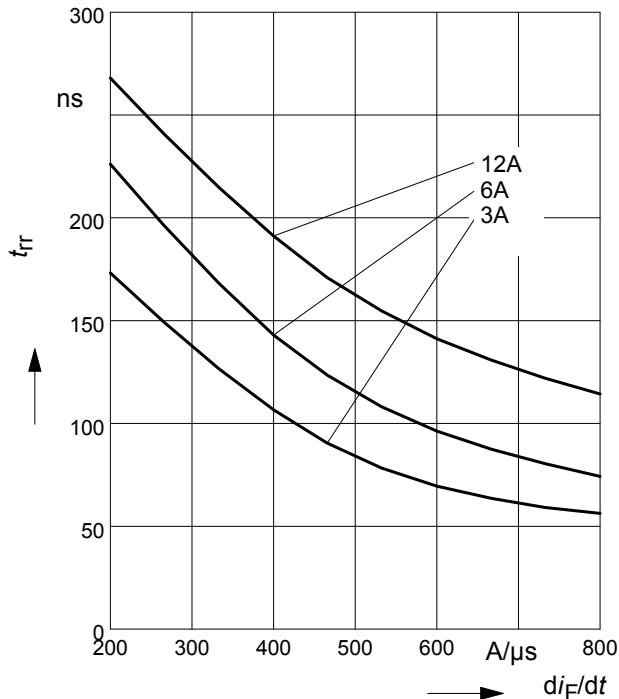
$$V_F = f(T_j)$$



5 Typ. reverse recovery time

$$t_{rr} = f(dI_F/dt)$$

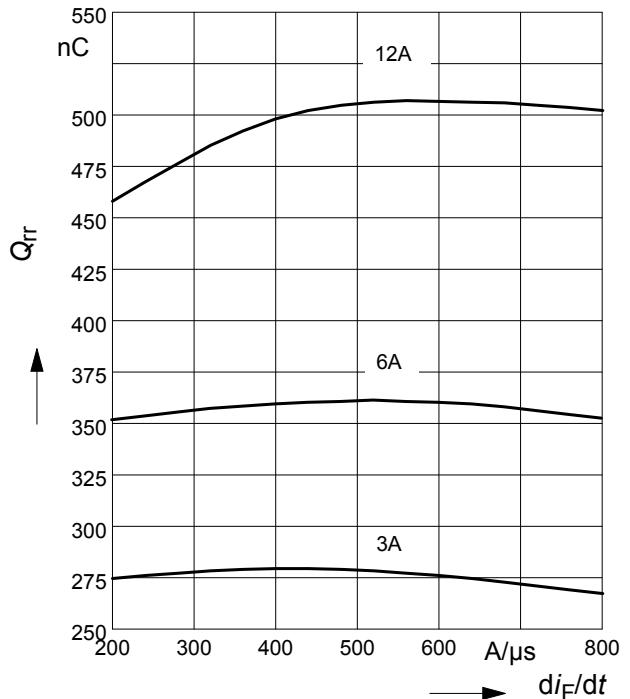
parameter: $V_R = 400V$, $T_j = 125^\circ C$



6 Typ. reverse recovery charge

$$Q_{rr} = f(dI_F/dt)$$

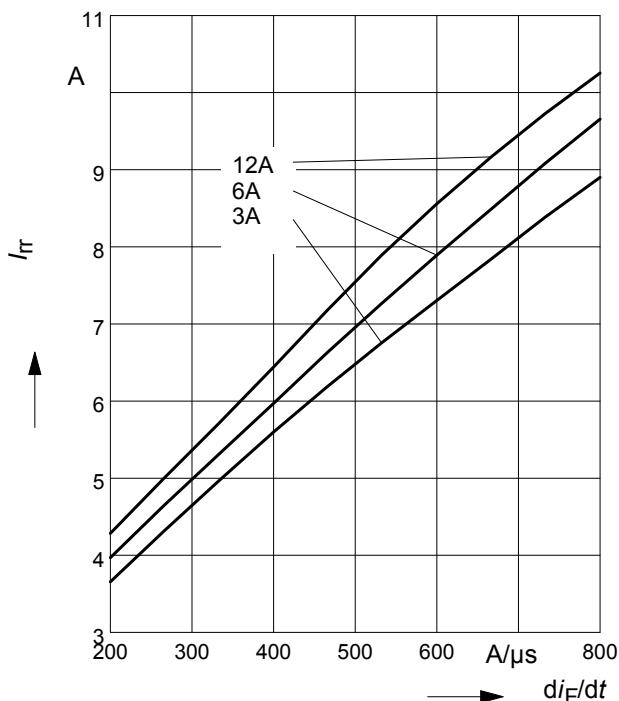
parameter: $V_R = 400V$, $T_j = 125^\circ C$



7 Typ. reverse recovery current

$$I_{rr} = f(dI_F/dt)$$

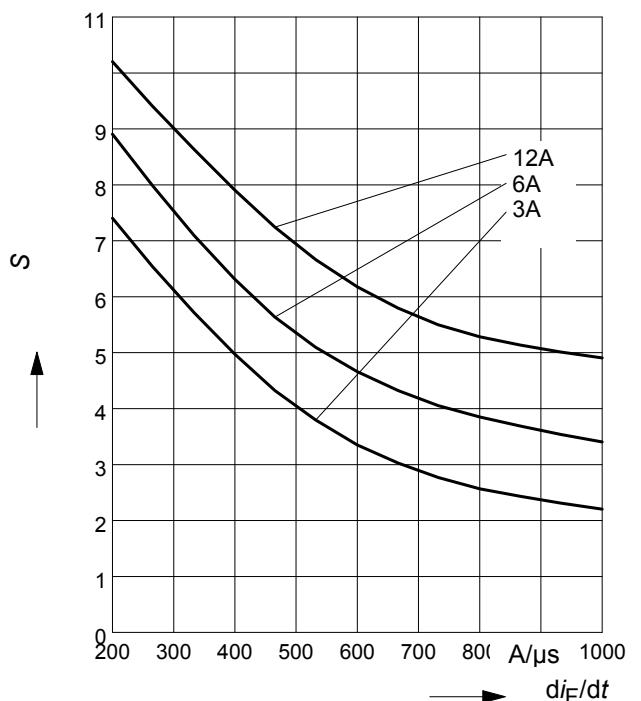
parameter: $V_R = 400V$, $T_j = 125^\circ C$



8 Typ. reverse recovery softness factor

$$S = f(dI_F/dt)$$

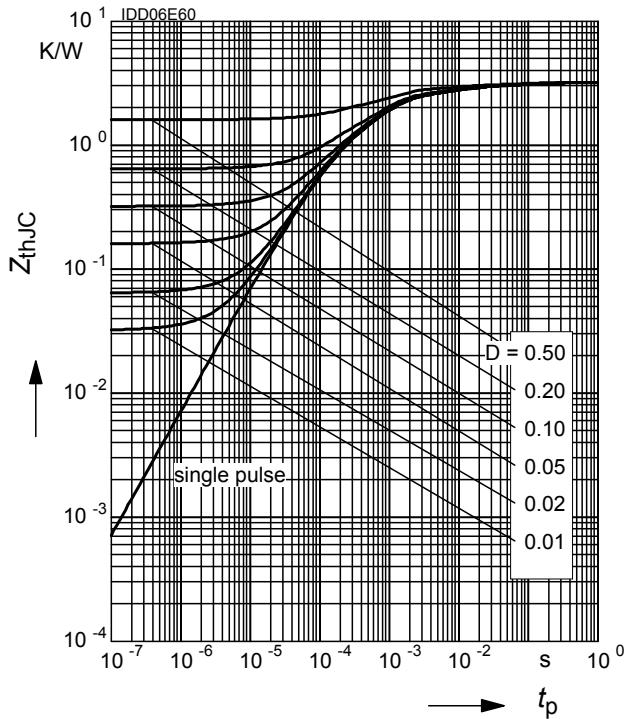
parameter: $V_R = 400V$, $T_j = 125^\circ C$

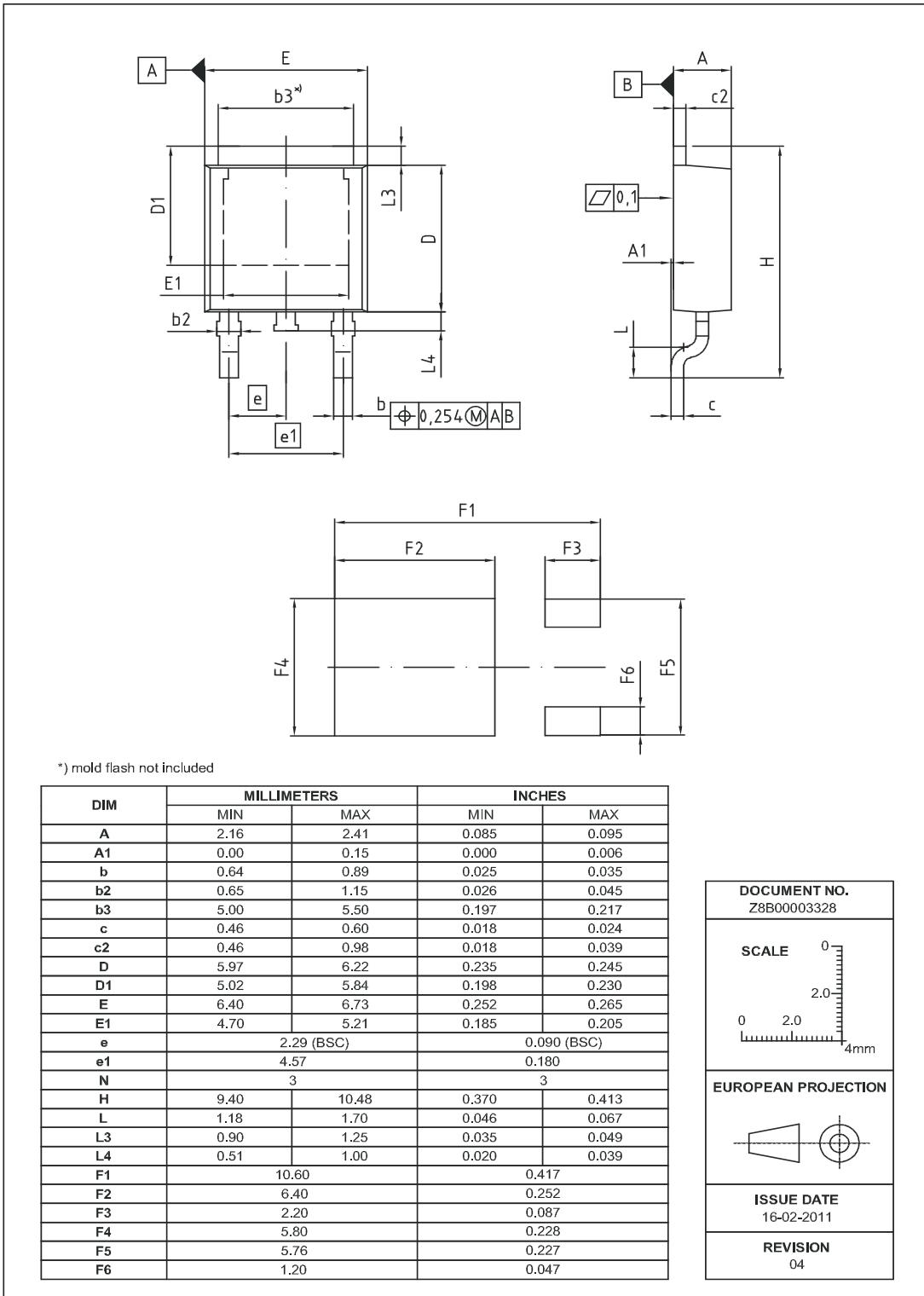


9 Max. transient thermal impedance

$$Z_{\text{thJC}} = f(t_p)$$

parameter : $D = t_p/T$



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